ANALOG DEVICES

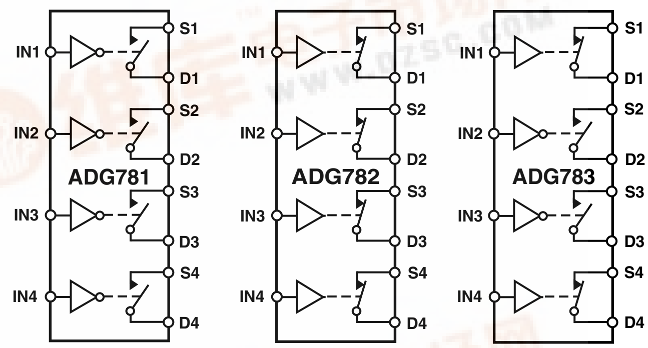
2.5 Ω Quad SPST Switches in Chip Scale Package

ADG781/ADG782/ADG783

FEATURES
- 1.8 V to 5.5 V Single Supply
- Low On Resistance (2.5 Ω Typ)
- Low On-Resistance Flatness (0.5 Ω)
- –3 dB Bandwidth > 200 MHz
- Rail-to-Rail Operation
- 20-Lead 4 mm × 4 mm Chip Scale Package
- Fast Switching Times
  - t_{ON} = 16 ns
  - t_{OFF} = 10 ns
- Typical Power Consumption (< 0.01 μW)
- TTL/CMOS Compatible
- For Functionally Equivalent Devices in 16-Lead TSSOP and SOIC Packages, See ADG711/ADG712/ADG713

APPLICATIONS
- Battery Powered Systems
- Communication Systems
- Sample Hold Systems
- Audio Signal Routing
- Video Switching
- Mechanical Reed Relay Replacement

FUNCTIONAL BLOCK DIAGRAMS



SWITCHES SHOWN FOR A LOGIC "1" INPUT

GENERAL DESCRIPTION

The ADG781, ADG782, and ADG783 are monolithic CMOS devices containing four independently selectable switches. These switches are designed on an advanced submicron process that provides low power dissipation and high switching speed, low on resistance, low leakage currents and high bandwidth.

They are designed to operate from a single 1.8 V to 5.5 V supply, making them ideal for use in battery powered instruments and with the new generation of DACs and ADCs from Analog Devices. Fast switching times and high bandwidth make the part suitable for video signal switching.

The ADG781, ADG782, and ADG783 contain four independent single-pole/single throw (SPST) switches. The ADG781 and ADG782 differ only in that the digital control logic is inverted. The ADG781 switches are turned on with a logic low on the appropriate control input, while a logic high is required to turn on the switches of the ADG782. The ADG783 contains two switches whose digital control logic is similar to the ADG781, while the logic is inverted on the other two switches.

Each switch conducts equally well in both directions when ON. The ADG783 exhibits break-before-make switching action.

The ADG781/ADG782/ADG783 are available in 20-lead chip scale packages.

PRODUCT HIGHLIGHTS

1. 20-Lead 4 mm × 4 mm Chip Scale Package (CSP).
2. 1.8 V to 5.5 V Single Supply Operation. The ADG781, ADG782, and ADG783 offer high performance and are fully specified and guaranteed with 3 V and 5 V supply rails.
3. Very Low R_{ON} (4.5 Ω max at 5 V, 8 Ω max at 3 V). At supply voltage of 1.8 V, R_{ON} is typically 35 Ω over the temperature range.
4. Low On-Resistance Flatness.
5. –3 dB Bandwidth >200 MHz.
6. Low Power Dissipation. CMOS construction ensures low power dissipation.
7. Fast t_{ON}/t_{OFF}.
8. Break-Before-Make Switching. This prevents channel shorting when the switches are configured as a multiplexer (ADG783 only).

REV. A

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ADG781/ADG782/ADG783–SPECIFICATIONS

(V_{DD} = 5 V ± 10%, GND = 0 V. All specifications –40°C to +85°C unless otherwise noted.)

Parameter	B Version +25°C	B Version –40°C to +85°C	Unit	Test Conditions/Comments
ANALOG SWITCH				
Analog Signal Range		0 V to V_{DD}	V	
On Resistance (R_{ON})	2.5		Ω typ	V_S = 0 V to V_{DD}, I_S = –10 mA;
	4	4.5	Ω max	Test Circuit 1
On-Resistance Match Between		0.05	Ω typ	V_S = 0 V to V_{DD}, I_S = –10 mA
Channels (ΔR_{ON})		0.4	Ω max	
On-Resistance Flatness ($R_{FLAT(ON)}$)	0.5		Ω typ	V_S = 0 V to V_{DD}, I_S = –10 mA
		1.0	Ω max	
LEAKAGE CURRENTS				V_{DD} = 5.5 V;
Source OFF Leakage I_S (OFF)	±0.01		nA typ	V_S = 4.5 V/1 V, V_D = 1 V/4.5 V;
	±0.1	±0.2	nA max	Test Circuit 2
Drain OFF Leakage I_D (OFF)	±0.01		nA typ	V_S = 4.5 V/1 V, V_D = 1 V/4.5 V;
	±0.1	±0.2	nA max	Test Circuit 2
Channel ON Leakage I_D, I_S (ON)	±0.01		nA typ	V_S = V_D = 1 V, or 4.5 V;
	±0.1	±0.2	nA max	Test Circuit 3
DIGITAL INPUTS				
Input High Voltage, V_{INH}		2.4	V min	
Input Low Voltage, V_{INL}		0.8	V max	
Input Current				
I_{INL} or I_{INH}	0.005		μA typ	V_{IN} = V_{INL} or V_{INH}
		±0.1	μA max	
DYNAMIC CHARACTERISTICS[2]				
t_{ON}	11		ns typ	R_L = 300 Ω, C_L = 35 pF,
		16	ns max	V_S = 3 V; Test Circuit 4
t_{OFF}	6		ns typ	R_L = 300 Ω, C_L = 35 pF,
		10	ns max	V_S = 3 V; Test Circuit 4
Break-Before-Make Time Delay, t_D	6		ns typ	R_L = 300 Ω, C_L = 35 pF,
(ADG783 Only)		1	ns min	V_{S1} = V_{S2} = 3 V; Test Circuit 5
Charge Injection	3		pC typ	V_S = 2 V; R_S = 0 Ω, C_L = 1 nF; Test Circuit 6
Off Isolation	–58		dB typ	R_L = 50 Ω, C_L = 5 pF, f = 10 MHz
	–78		dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; Test Circuit 7
Channel-to-Channel Crosstalk	–90		dB typ	R_L = 50 Ω, C_L = 5 pF, f = 10 MHz; Test Circuit 8
Bandwidth –3 dB	200		MHz typ	R_L = 50 Ω, C_L = 5 pF; Test Circuit 9
C_S (OFF)	10		pF typ	f = 1 MHz
C_D (OFF)	10		pF typ	f = 1 MHz
C_D, C_S (ON)	22		pF typ	f = 1 MHz
POWER REQUIREMENTS				V_{DD} = 5.5 V
I_{DD}	0.001		μA typ	Digital Inputs = 0 V or 5.5 V
		1.0	μA max	

NOTES

[1]Temperature ranges are as follows: B Version: –40°C to +85°C.

[2]Guaranteed by design, not subject to production test.

Specifications subject to change without notice.

SPECIFICATIONS[1]

(V_{DD} = 3 V ±10%, GND = 0 V. All specifications –40°C to +85°C unless otherwise noted.)

Parameter	B Version +25°C	B Version –40°C to +85°C	Unit	Test Conditions/Comments
ANALOG SWITCH				
Analog Signal Range		0 V to V_{DD}	V	
On Resistance (R_{ON})	5	5.5	Ω typ	V_S = 0 V to V_{DD}, I_S = –10 mA;
		10	Ω max	Test Circuit 1
On-Resistance Match Between	0.1		Ω typ	V_S = 0 V to V_{DD}, I_S = –10 mA
Channels (ΔR_{ON})		0.5	Ω max	
On-Resistance Flatness ($R_{FLAT(ON)}$)		2.5	Ω typ	V_S = 0 V to V_{DD}, I_S = –10 mA
LEAKAGE CURRENTS				V_{DD} = 3.3 V;
Source OFF Leakage I_S (OFF)	±0.01		nA typ	V_S = 3 V/1 V, V_D = 1 V/3 V;
	±0.1	±0.2	nA max	Test Circuit 2
Drain OFF Leakage I_D (OFF)	±0.01		nA typ	V_S = 3 V/1 V, V_D = 1 V/3 V;
	±0.1	±0.2	nA max	Test Circuit 2
Channel ON Leakage I_D, I_S (ON)	±0.01		nA typ	V_S = V_D = 1 V, or 3 V;
	±0.1	±0.2	nA max	Test Circuit 3
DIGITAL INPUTS				
Input High Voltage, V_{INH}		2.0	V min	
Input Low Voltage, V_{INL}		0.8	V max	
Input Current				
I_{INL} or I_{INH}	0.005		μA typ	V_{IN} = V_{INL} or V_{INH}
		±0.1	μA max	
DYNAMIC CHARACTERISTICS[2]				
t_{ON}	13		ns typ	R_L = 300 Ω, C_L = 35 pF,
		20	ns max	V_S = 2 V; Test Circuit 4
t_{OFF}	7		ns typ	R_L = 300 Ω, C_L = 35 pF,
		12	ns max	V_S = 2 V; Test Circuit 4
Break-Before-Make Time Delay, t_D	7		ns typ	R_L = 300 Ω, C_L = 35 pF,
(ADG783 Only)		1	ns min	V_{S1} = V_{S2} = 2 V; Test Circuit 5
Charge Injection	3		pC typ	V_S = 1.5 V; R_S = 0 Ω, C_L = 1 nF; Test Circuit 6
Off Isolation	–58		dB typ	R_L = 50 Ω, C_L = 5 pF, f = 10 MHz
	–78		dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; Test Circuit 7
Channel-to-Channel Crosstalk	–90		dB typ	R_L = 50 Ω, C_L = 5 pF, f = 10 MHz; Test Circuit 8
Bandwidth –3 dB	200		MHz typ	R_L = 50 Ω, C_L = 5 pF; Test Circuit 9
C_S (OFF)	10		pF typ	f = 1 MHz
C_D (OFF)	10		pF typ	f = 1 MHz
C_D, C_S (ON)	22		pF typ	f = 1 MHz
POWER REQUIREMENTS				V_{DD} = 3.3 V
I_{DD}	0.001		μA typ	Digital Inputs = 0 V or 3.3 V
		1.0	μA max	

NOTES
[1]Temperature ranges are as follows: B Version: –40°C to +85°C.
[2]Guaranteed by design, not subject to production test.
Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS[1]

(T_A = 25°C unless otherwise noted.)

V_{DD} to GND	–0.3 V to +6 V
Analog, Digital Inputs[2]	–0.3 V to V_{DD} + 0.3 V or 30 mA, Whichever Occurs First
Continuous Current, S or D	30 mA
Peak Current, S or D	100 mA (Pulsed at 1 ms, 10% Duty Cycle max)
Operating Temperature Range	
Industrial (B Version)	–40°C to +85°C
Storage Temperature Range	–65°C to +150°C
Junction Temperature	150°C
Chip Scale Package	
θ_{JA} Thermal Impedance	32°C/W
Lead Temperature, Soldering (10 sec)	300°C
IR Reflow (<20 sec)	235°C

NOTES

[1]Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

[2]Overvoltages at IN, S, or D will be clamped by internal diodes. Current should be limited to the maximum ratings given.

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
ADG781BCP	–40°C to +85°C	20-Lead Chip Scale (CSP)	CP-20
ADG782BCP	–40°C to +85°C	20-Lead Chip Scale (CSP)	CP-20
ADG783BCP	–40°C to +85°C	20-Lead Chip Scale (CSP)	CP-20

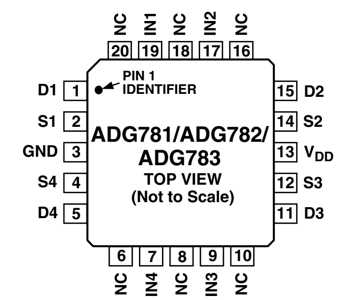
Table I. Truth Table (ADG781/ADG782)

ADG781 In	ADG782 In	Switch Condition
0	1	ON
1	0	OFF

Table II. Truth Table (ADG783)

Logic	Switch 1, 4	Switch 2, 3
0	OFF	ON
1	ON	OFF

PIN CONFIGURATION (CSP)



NC = NO CONNECT
EXPOSED PAD TIED TO SUBSTRATE, GND

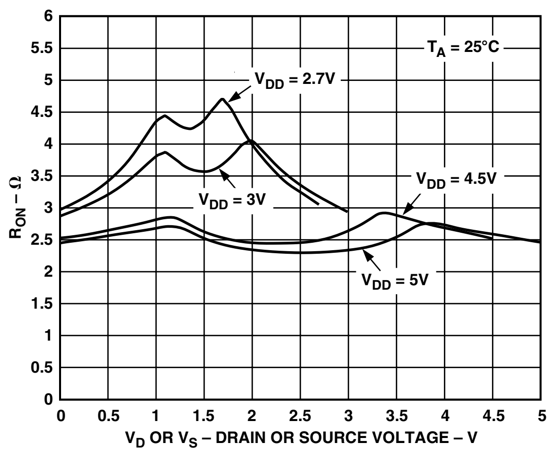
CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the ADG781/ADG782/ADG783 feature proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high-energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

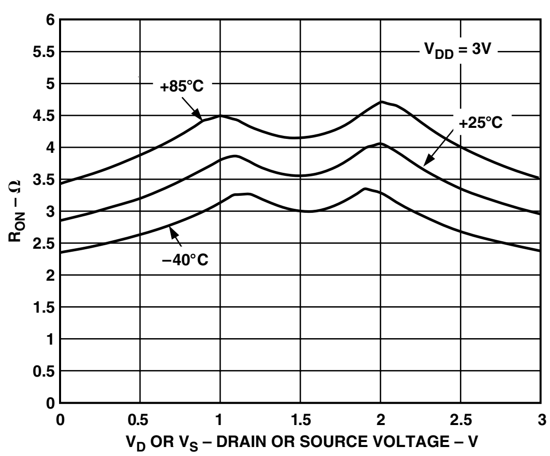
TERMINOLOGY

V_{DD}	Most positive power supply potential.
GND	Ground (0 V) reference.
S	Source terminal. May be an input or output.
D	Drain terminal. May be an input or output.
IN	Logic control input.
R_{ON}	Ohmic resistance between D and S.
ΔR_{ON}	On-resistance match between any two channels (i.e., R_{ON} max and R_{ON} min).
$R_{FLAT(ON)}$	Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.
I_S (OFF)	Source leakage current with the switch "OFF."
I_D (OFF)	Drain leakage current with the switch "OFF."
I_D, I_S (ON)	Channel leakage current with the switch "ON."
V_D (V_S)	Analog voltage on terminals D, S.
C_S (OFF)	"OFF" switch source capacitance.
C_D (OFF)	"OFF" switch drain capacitance.
C_D, C_S (ON)	"ON" switch capacitance.
t_{ON}	Delay between applying the digital control input and the output switching on.
t_{OFF}	Delay between applying the digital control input and the output switching off.
t_D	"OFF" time or "ON" time measured between the 90% points of both switches, when switching from one address state to another (ADG783 only).
Crosstalk	A measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.
Off Isolation	A measure of unwanted signal coupling through an "OFF" switch.
Charge Injection	A measure of the glitch impulse transferred from the digital input to the analog output during switching.
On Response	The frequency response of the "ON" switch.
On Loss	The loss due to the on resistance of the switch.

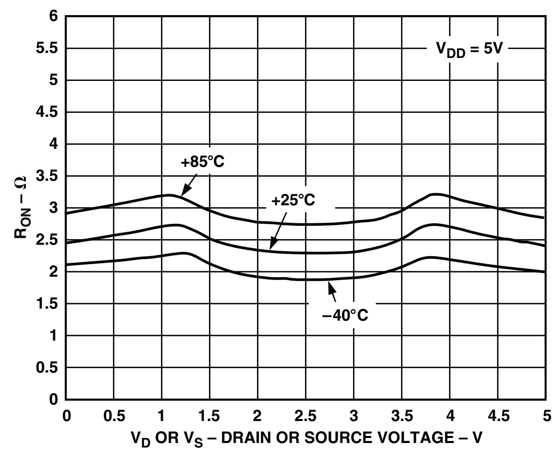
Typical Performance Characteristics



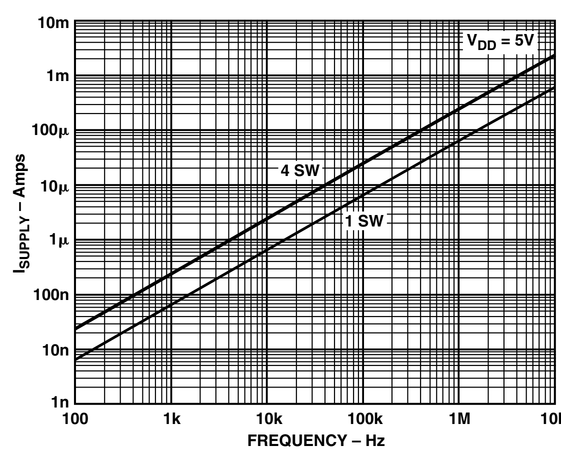
TPC 1. On Resistance as a Function of V_D (V_S)



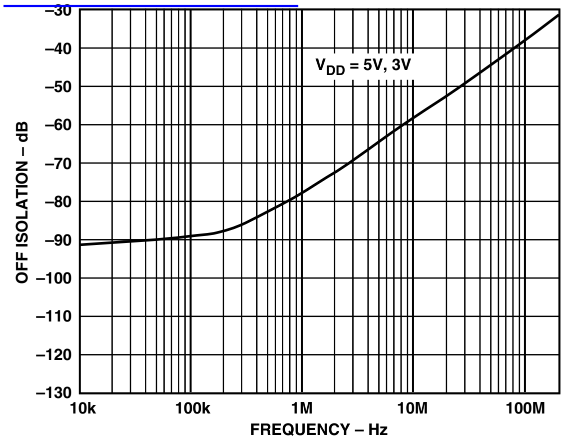
TPC 2. On Resistance as a Function of V_D (V_S) for Different Temperatures V_{DD} = 3 V



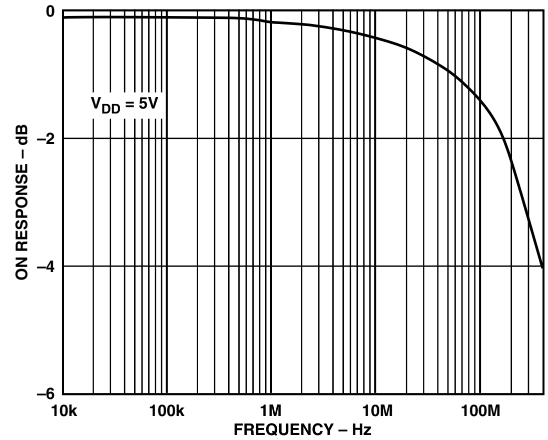
TPC 3. On Resistance as a Function of V_D (V_S) for Different Temperatures V_{DD} = 5 V



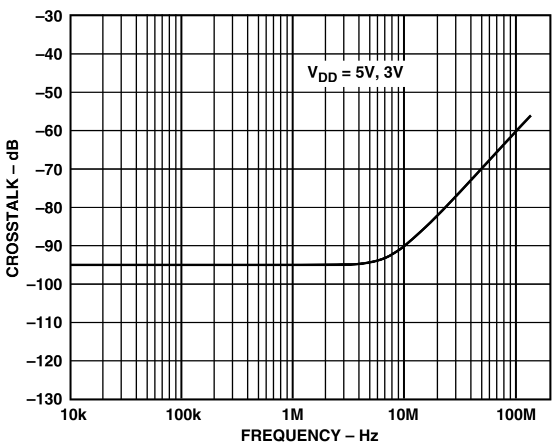
TPC 4. Supply Current vs. Input Switching Frequency



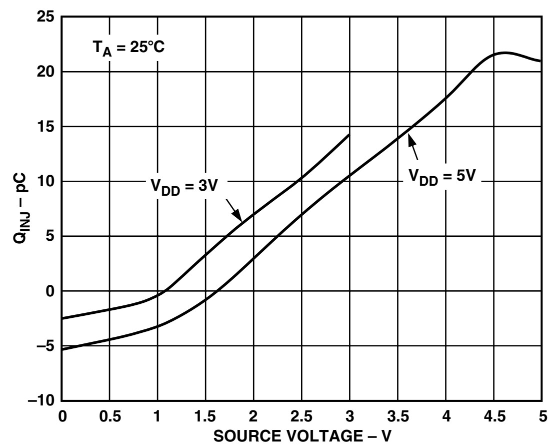
TPC 5. *Off Isolation vs. Frequency*



TPC 7. *On Response vs. Frequency*



TPC 6. *Crosstalk vs. Frequency*



TPC 8. *Charge Injection vs. Source Voltage*

APPLICATIONS

Figure 1 illustrates a photodetector circuit with programmable gain. An AD820 is used as the output operational amplifier. With the resistor values shown in the circuit, and using different combinations of the switches, gain in the range of 2 to 16 can be achieved.

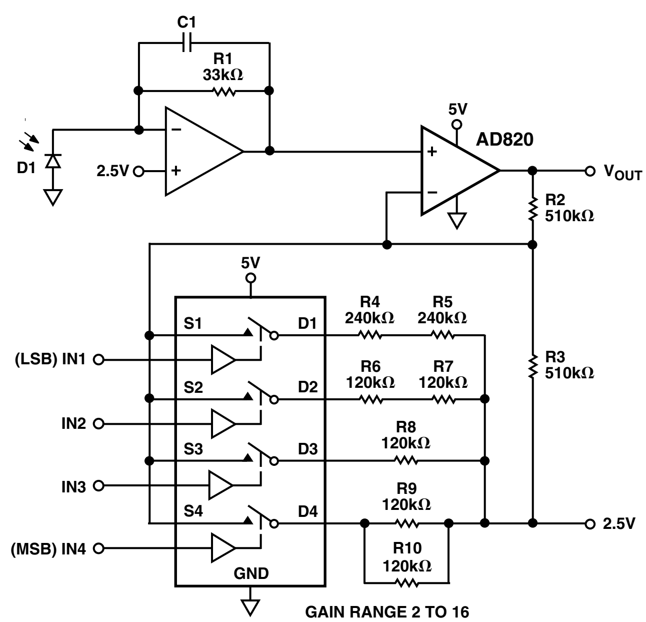
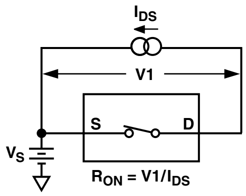
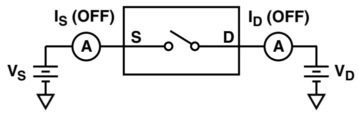


Figure 1. Photodetector Circuit with Programmable Gain

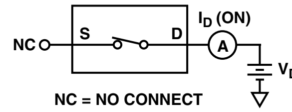
Test Circuits



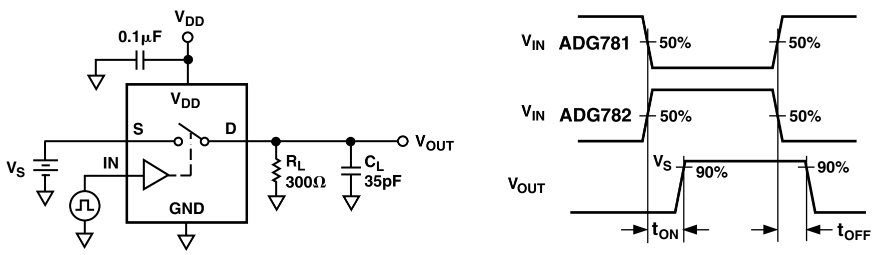
Test Circuit 1. On Resistance



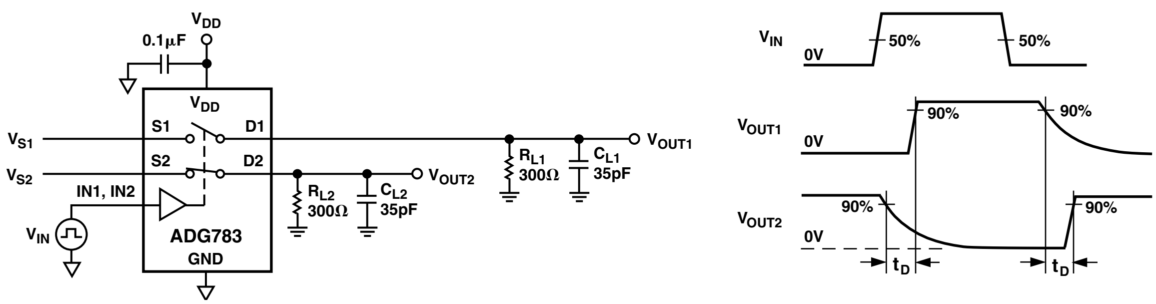
Test Circuit 2. Off Leakage



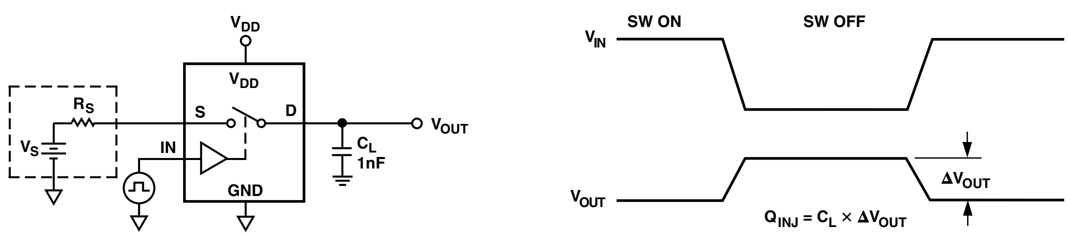
Test Circuit 3. On Leakage



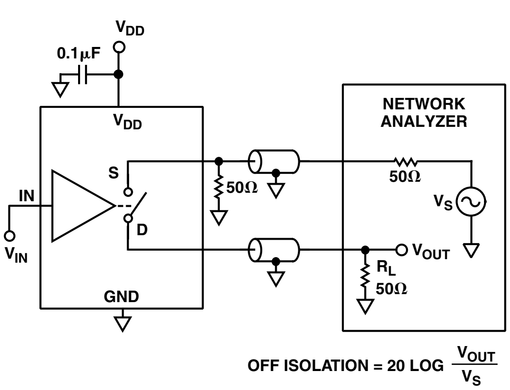
Test Circuit 4. Switching Times



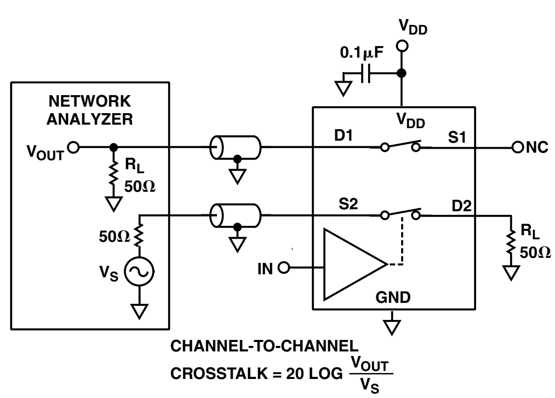
Test Circuit 5. Break-Before-Make Time Delay, t_D



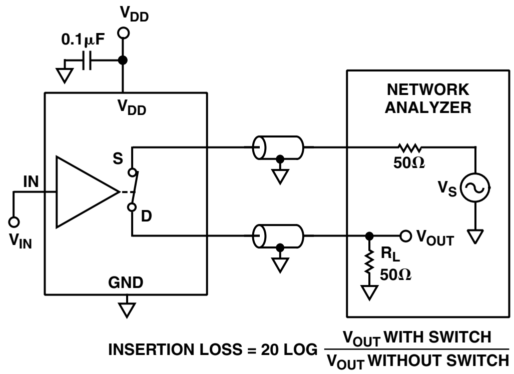
Test Circuit 6. Charge Injection



Test Circuit 7. Off Isolation



Test Circuit 8. Channel-to-Channel Crosstalk



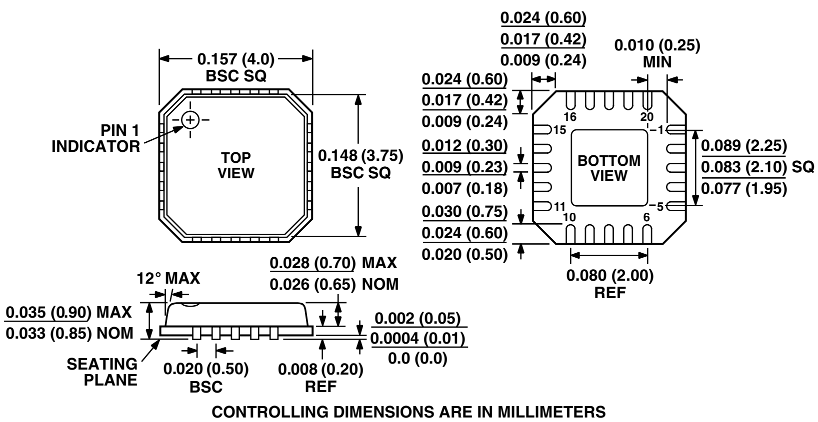
Test Circuit 9. Bandwidth

C02372–0–3/02(A)

OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

20-Lead CSP
(CP-20)



Revision History

Location	Page
Data Sheet changed from REV. 0 to REV. A.	
Edits to Typical Performance Characteristics	5–6
Changes to OUTLINE DIMENSIONS drawing	8

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